Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Gla	ass
Ov	erall Length:
0.2	00 inches
Те	rminal Length:
0.5	00 inches
Ov	erall Diameter:
0.0	90 inches
Joi	int Electronic Device Engineering Council/jedec/case Outline Designation:
Do	-35
Мо	ounting Method:
Те	rminal
Fea	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Vo	Itage Rating In Volts Per Characteristic:
10.	0 regulator voltage
Vo	Itage Tolerance In Percent:
-5.0	0/+5.0
Cu	rrent Rating Per Characteristic:
5.0	0 milliamperes source cutoff current horsepower metric
Po	wer Rating Per Characteristic:
0.4	watts small-signal input power, common-collector preset
Ма	ximum Operating Tempurature Per Measurement Point:
	5.0 degrees celsius junction
Те	rminal Type And Quantity:
2 u	ninsulated wire lead
Sh	elf Life:
N/a	
Un	it Of Measure:
	militarization:
No	
Fiig	-
A1	10a0